



BC846A-BC848C

NPN SMALL SIGNAL TRANSISTOR IN SOT23

Features

- Ideally Suited for Automatic Insertion
- Complementary PNP Types: BC856 BC858
- For switching and AF Amplifier Applications
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP capable (Note 4)

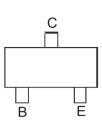
Mechanical Data

- Case: SOT23
- Case material: molded plastic, "Green" molding compound UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (63)
- Weight: 0.008 grams (Approximate)



Top View

Device Symbol



Top View Pin-Out

Ordering Information (Notes 4 & 5)

Product	Compliance	Marking	Reel size (inches)	Quantity per reel
BC846A-7-F	AEC-Q101	K1Q	7	3,000
BC846AQ-7-F	Automotive	K1Q	7	3,000
BC846B-7-F	AEC-Q101	K1R	7	3,000
BC846BQ-7-F	Automotive	K1R	7	3,000
BC846B-13-F	AEC-Q101	K1R	13	10,000
BC846BQ-13-F	Automotive	K1R	13	10,000
BC847A-7-F	AEC-Q101	K1Q	7	3,000
BC847AQ-7-F	Automotive	K1Q	7	3,000
BC847A-13-F	AEC-Q101	K1Q	13	10,000
BC847B-7-F	AEC-Q101	K1R	7	3,000
BC847BQ-7-F	Automotive	K1R	7	3,000

Product	Compliance	Marking	Reel size (inches)	Quantity per reel
BC847B-13-F	AEC-Q101	K1R	13	10,000
BC847C-7-F	AEC-Q101	K1M	7	3,000
BC847CQ-7-F	Automotive	K1M	7	3,000
BC847C-13-F	AEC-Q101	K1M	13	10,000
BC848A-7-F	AEC-Q101	K1Q	7	3,000
BC848B-7-F	AEC-Q101	K1R	7	3,000
BC848B-13-F	AEC-Q101	K1R	13	10,000
BC848C-7-F	AEC-Q101	K1M	7	3,000
BC848CQ-7-F	Automotive	K1M	7	3,000

Notes:

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

 See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen and Antimony free, "Green" and Lead-Free.

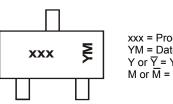
3. Halogen and Antimony free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

A Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally

the same, except where specified. For more information, please refer to http://www.diodes.com/quality/product_compliance_definitions/.

5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



xxx = Product Type Marking Code YM = Date Code Marking Y or \overline{Y} = Year (ex: Y = 2011)

M or \overline{M} = Month (ex: 9 = September)

Date Code Key												
Year	2010		2011	2012		2013	2014		2015	2016		2017
Code	Х		Y	Z		А	В		С	D		E
Manth	lan	Fab	Man	A	Mari		11	Aug	Sep	Oct	Nov	Dec
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Seh	001	NOV	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Character	istic	Symbol	Value	Unit
	BC846		80	
Collector-Base Voltage	BC847	V _{CBO}	50	V
	BC848		30	
	BC846		65	
Collector-Emitter Voltage	BC847	V _{CEO}	45	V
	BC848		30	
Emitter-Base Voltage	BC846, BC847	M	6.0	V
Emilier-Base vollage	BC848	V _{EBO}	5.0	v
Continuous Collector Current		lc	100	mA
Peak Collector Current		I _{CM}	200	mA
Peak Emitter Current		I _{EM}	200	mA

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Power Dissipation	(Note 6)	Р	310	mW	
	(Note 7)	- P _D	350	TIVV	
Thermal Decistance, Junction to Ambient	(Note 6)	D	403	0000	
Thermal Resistance, Junction to Ambient	(Note 7)	R _{0JA}	357	°C/W	
Thermal Resistance, Junction to Leads (Note 8)		$R_{\theta JL}$	350	°C/W	
Operating and Storage Temperature Range		T _J ,T _{STG}	-65 to +150	°C	

ESD Ratings (Note 9)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Notes:

For a device mounted on minimum recommended pad layout 1oz copper that is on a single-sided FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.

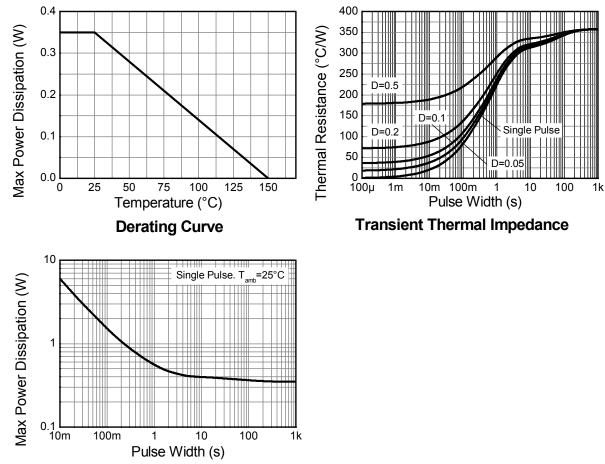
7. Same as note (6), except the device is mounted on 15 mm x 15mm 1oz copper.

8. Thermal resistance from junction to solder-point (at the end of the leads).

9. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



Thermal Characteristics and Derating Information



Pulse Power Dissipation



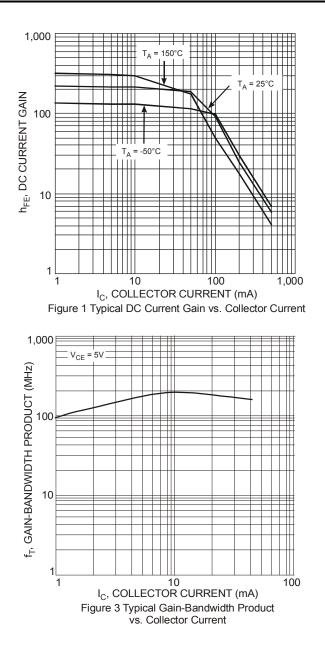
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

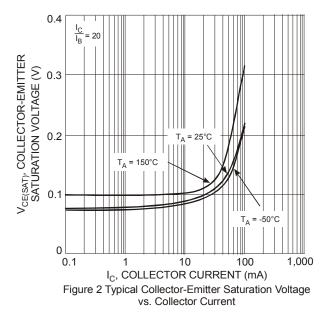
Ch	aracteristic		Symbol	Min	Тур	Max	Unit	Test Condition	
		BC846		80					
Collector-Base Breakdown Voltage		BC847	BV CBO	50	—	—	V	I _C = 10μA	
		BC848		30					
Collector Emitter Brookdown	Valtaga	BC846		65		_			
Collector-Emitter Breakdown (Note 10)	vollage	BC847	BV _{CEO}	45	—		V	I _C = 10mA	
(10010-10)		BC848		30					
Emitter-Base Breakdown Vo	Itago	BC846 / BC847	BVEBO	6			V	I _E = 1μΑ	
Emilier-Base Breakdown vo	llage	BC848	DVEBO	5	_		v	IE - ΤμΑ	
Collector Cutoff Current			I _{CBO}			15	nA	V _{CB} = 30V	
			ICBO			5	μA	V _{CB} = 30V, T _J = +150°C	
		BC846				15		V _{CE} = 80V	
Collector Emitter Cutoff Curr	ent	BC847	ICES	_	—	15	nA	V _{CE} = 50V	
		BC848				15		V _{CE} = 30V	
Emitter Base Cutoff Current			I _{EBO}	_	_	100	nA	V _{EB} = 5V	
Creat Circal Current Cain	BC846A / E	C847A / BC848A			200		_		
Small Signal Current Gain (Note 10)		C847B / BC848B	h _{fe}	—	330	_			
(Note 10)	BC847	7C / BC848C			600				
Input Impedance	BC846A / BC847A / BC848A BC846B / BC847B / BC848B			_	2.7		kΩ		
(Note 10)			h _{ie}		4.5	—			
	BC847C / BC848C				8.7			I _C = 2.0mA, V _{CE} = 5V	
Output Admittance	BC846A / BC847A / BC848A BC846B / BC847B / BC848B		h _{oe}	_	18		μS	f=1.0kHz	
(Note 10)					30	—			
(11010-10)		7C / BC848C			60			-	
Reverse Voltage Transfer		C847A / BC848A			1.5x10 ⁻⁴				
Ratio (Note 10)	BC846B / BC847B / BC848B		h _{re}	—	2x10 ⁻⁴	—	—		
		7C / BC848C			3x10 ⁻⁴			<u> </u>	
		C847A / BC848A		110	180	220			
DC Current Gain (Note 10)	BC846B / BC847B / BC848B		h _{FE}	200	290	450		I _C = 2.0mA, V _{CE} = 5V	
		7C / BC848C		420	520	800			
Collector-Emitter Saturation	Voltage		V _{CE(sat)}	_	90	250	mV	$I_{\rm C}$ = 10mA, $I_{\rm B}$ = 0.5mA	
(Note 10)			- 01(301)		200	600		I _C = 100mA, I _B = 5.0mA	
Base-Emitter Turn-On Voltag	e(Note 10)		V _{BE(on)}	580	660	700	mV	I_C = 2mA, V_{CE} = 5V	
	30(11010-10)		▼ BE(011)	_	—	770		I_{C} = 10mA, V_{CE} = 5V	
Base-Emitter Saturation Volt	age(Note 10)		V _{BE(sat)}		700	_	mV	I _C = 10mA, I _B = 0.5mA	
Base-Emitter Saturation Voltage(Note 10)		VBE(sat)	_	900	_	IIIV	I _C = 100mA, I _B = 5mA		
Output Capacitance			Cobo	_	3	_	pF	V _{CB} = 10V, f = 1.0MHz	
Transition Frequency			f _T	100	300		MHz	V _{CE} = 5V, I _C = 10mA, f = 100MHz	
Noise Figure			NF	_	2	10	dB	V _{CE} =5V, I _C =200μA R _S =2kΩ, f=1kHz ∆f=200Hz	

Note: 10. Measured under pulsed conditions. Pulse width \leq 300µs. Duty cycle \leq 2%



Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

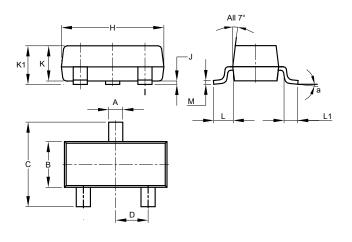






Package Outline Dimensions

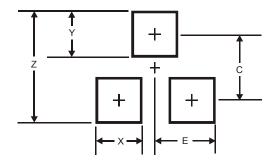
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



	SOT23								
Dim	Min	Max	Тур						
Α	0.37	0.51	0.40						
В	1.20	1.40	1.30						
С	2.30	2.50	2.40						
D	0.89	1.03	0.915						
F	0.45	0.60	0.535						
G	1.78	2.05	1.83						
Н	2.80	3.00	2.90						
J	0.013	0.10	0.05						
κ	0.890	1.00	0.975						
K1	0.903	1.10	1.025						
L	0.45	0.61	0.55						
L1	0.25	0.55	0.40						
М	0.085	0.150	0.110						
а	8°								
All	Dimens	ions in	mm						

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Z	2.9
Х	0.8
Y	0.9
С	2.0
E	1.35



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